

MOSFETs Silicon P-Channel MOS (U-MOSVI)

XPN27016MC

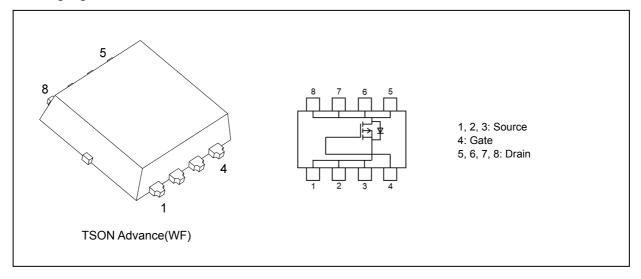
1. Applications

- · Automotive
- · Switching Voltage Regulators
- · DC-DC Converters
- · Motor Drivers

2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 21.0 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (4) Low leakage current: $I_{DSS} = -10 \mu A \text{ (max) (V}_{DS} = -60 \text{ V)}$
- (5) Enhancement mode: V_{th} = -1.0 to -2.1 V (V_{DS} = -10 V, I_D = -0.3 mA)

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (T_a = 25 °C unless otherwise specified)

Characteristics				Rating	Unit	
Drain-source voltage			V_{DSS}	-60	V	
Gate-source voltage			V _{GSS}	+10/-20		
Drain current (DC)		(Note 1)	I _D	-25	Α	
Drain current (pulsed)		(Note 1)	I _{DP}	-50		
Power dissipation	(T _c = 25 °C)		P_{D}	100	W	
Power dissipation	(t = 10 s)	(Note 2)		2.27		
Power dissipation	(t = 10 s)	(Note 3)		0.84		
Single-pulse avalanche energy		(Note 4)	E _{AS}	71	mJ	
Single-pulse avalanche current			I _{AS}	-25	Α	
Channel temperature		(Note 5)	T _{ch}	175	°C	
Storage temperature		(Note 5)	T _{stg}	-55 to 175		

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

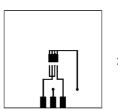
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit		
Channel-to-case thermal impedance	(T _c = 25 °C)		Z _{th(ch-c)}	1.5	°C/W
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 2)	Z _{th(ch-a)}	66	
Channel-to-ambient thermal impedance	(t = 10 s)	(Note 3)	Z _{th(ch-a)}	178	

- Note 1: Ensure that the channel temperature does not exceed 175 °C.
- Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1
- Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2
- Note 4: V_{DD} = -48 V, T_{ch} = 25 °C (initial), L = 87 μ H, R_{G} = 25 Ω , I_{AS} = -25 A, V_{GS} = 0/-15 V
- Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.





FR-4 $25.4 \times 25.4 \times 0.8$ (Unit: mm)

Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = +10/-20 V, V _{DS} = 0 V	_	_	±1	μА
Drain cut-off current	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	_	_	-10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = -10 mA, V _{GS} = 0 V	-60			V
	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-50			
Gate threshold voltage	V_{th}	$V_{DS} = -10 \text{ V}, I_{D} = -0.3 \text{ mA}$	-1.0	_	-2.1	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -4.5 V, I _D = -12.5 A	_	24.0	36.0	mΩ
		$V_{GS} = -10 \text{ V}, I_D = -12.5 \text{ A}$	_	21.0	27.3	

6.2. Dynamic Characteristics (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	2900	4060	pF
Reverse transfer capacitance	C _{rss}		_	220	308	
Output capacitance	C _{oss}		_	280	_	
Gate resistance	r _g		_	13	26	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	28	_	ns
Switching time (turn-on time)	t _{on}		_	38	_	
Switching time (fall time)	t _f		_	157	_	
Switching time (turn-off time)	t _{off}		_	576	_	

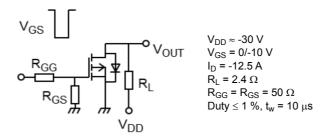


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)		$V_{DD} \approx -48 \text{ V}, V_{GS} = -10 \text{ V},$ $I_{D} = -25 \text{ A}$	_	71		nC
Gate-source charge 1	Q _{gs1}		_	4		
Gate-drain charge	Q_{gd}		_	19	_	

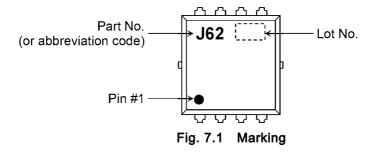
6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 6)	I _{DR}	_	_	_	-25	Α
Reverse drain current (pulsed)	(Note 6)	I _{DRP}	_	_	_	-50	
Diode forward voltage		V _{DSF}	I _{DR} = -25 A, V _{GS} = 0 V	_	_	1.2	V
Reverse recovery time		t _{rr}	I _{DR} = -25 A, V _{GS} = 0 V	_	55	_	ns
Reverse recovery charge		Q _{rr}	dl _{DR} /dt = 50 A/μs	-	33	_	nC

Note 6: Ensure that the channel temperature does not exceed 175 °C.



7. Marking





8. Characteristics Curves (Note)

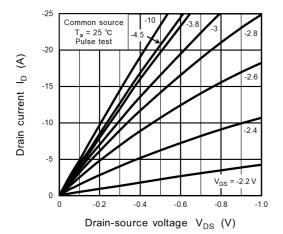


Fig. 8.1 I_D - V_{DS}

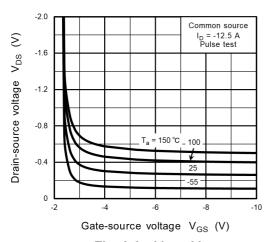


Fig. 8.3 V_{DS} - V_{GS}

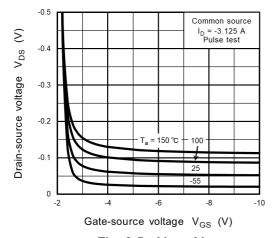


Fig. 8.5 V_{DS} - V_{GS}

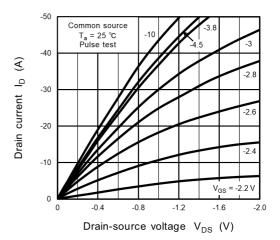


Fig. 8.2 I_D - V_{DS}

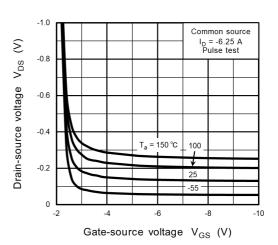


Fig. 8.4 VDS - VGS

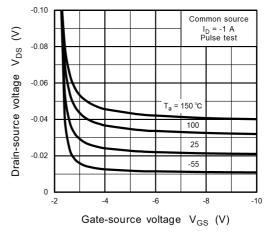


Fig. 8.6 V_{DS} - V_{GS}



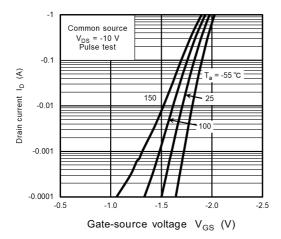


Fig. 8.7 I_D - V_{GS}

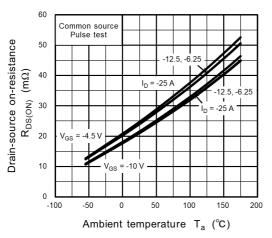


Fig. 8.9 R_{DS(ON)} - T_a

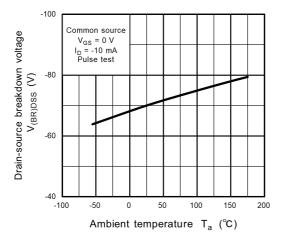


Fig. 8.11 V_{(BR)DSS} - T_a

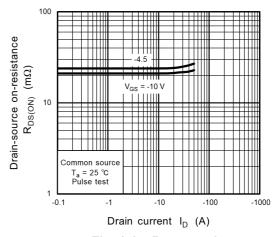


Fig. 8.8 R_{DS(ON)} - I_D

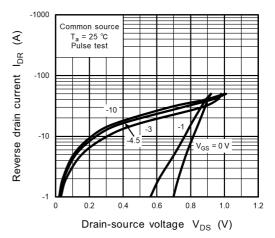


Fig. 8.10 I_{DR} - V_{DS}

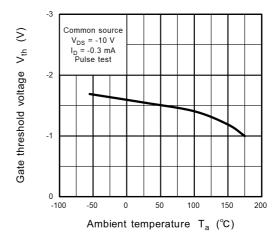


Fig. 8.12 V_{th} - T_a



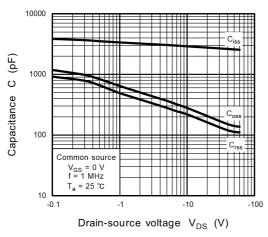


Fig. 8.13 Capacitance - V_{DS}

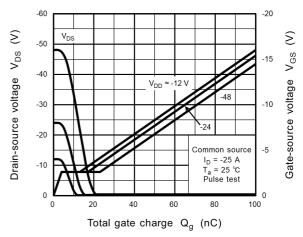


Fig. 8.14 Dynamic Input/Output Characteristics



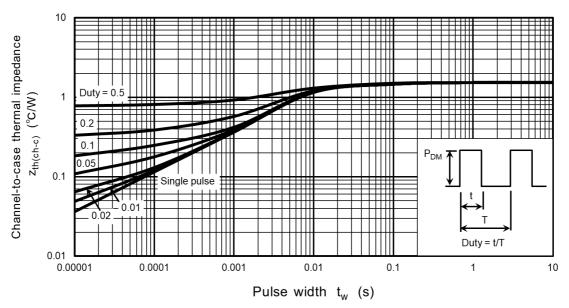
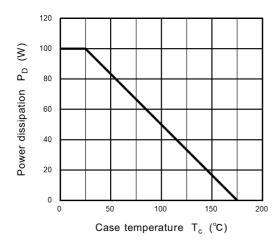


Fig. 8.15 $z_{th(ch-c)} - t_w$ (Guaranteed Maximum)



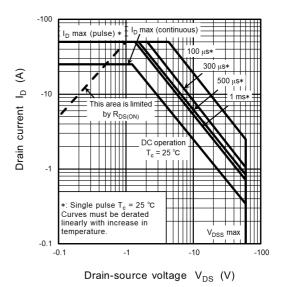


Fig. 8.16 P_D - T_c (Guaranteed Maximum)

Fig. 8.17 Safe Operating Area (Guaranteed Maximum)

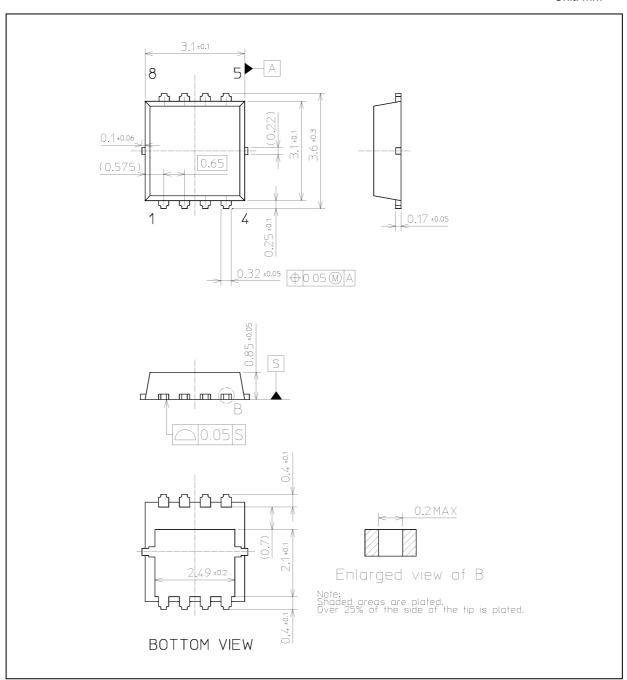
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

2024-12-16



Package Dimensions

Unit: mm



Weight: 0.029 g (typ.)

Package Name(s)			
TOSHIBA: 2-3X2A			
Nickname: TSON Advance(WF)			



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